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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/567,369	05/15/2006	Noboru Ichinose	PKHF-04053U/S	9867
21254	7590	08/19/2008	EXAMINER	
MCGINN INTELLECTUAL PROPERTY LAW GROUP, PLLC			SALERNO, SARAH KATE	
8321 OLD COURTHOUSE ROAD			ART UNIT	PAPER NUMBER
SUITE 200			2814	
VIENNA, VA 22182-3817			MAIL DATE	DELIVERY MODE
			08/19/2008	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Office Action Summary	Application No. 10/567,369	Applicant(s) ICHINOSE ET AL.
	Examiner SARAH K. SALERNO	Art Unit 2814

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --
Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
 - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
 - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED. (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(o).

Status

- 1) Responsive to communication(s) filed on 15 May 2006.
- 2a) This action is FINAL. 2b) This action is non-final.
- 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) Claim(s) 1-8 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) Claim(s) _____ is/are allowed.
- 6) Claim(s) 1-8 is/are rejected.
- 7) Claim(s) _____ is/are objected to.
- 8) Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) The specification is objected to by the Examiner.
- 10) The drawing(s) filed on _____ is/are: a) accepted or b) objected to by the Examiner.
 Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
 Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) All b) Some * c) None of:
1. Certified copies of the priority documents have been received.
 2. Certified copies of the priority documents have been received in Application No. _____.
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- 1) Notice of References Cited (PTO-892)
 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)
 3) Information Disclosure Statement(s) (PTO/SB/08)
 Paper No(s)/Mail Date 2/7/06
- 4) Interview Summary (PTO-413)
 Paper No(s)/Mail Date. _____
- 5) Notice of Informal Patent Application
 6) Other: _____

DETAILED ACTION

Specification

1. The title of the invention is not descriptive. A new title is required that is clearly indicative of the invention to which the claims are directed.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

3. Claims 1-8 are rejected under 35 U.S.C. 102(b) as being anticipated by Udagawa (JP 2000-349336).

Claim 1: Udagawa teaches a semiconductor layer, characterized by comprising:
a first layer made of a Ga_2O_3 system semiconductor (102); and
a second layer (103) obtained by replacing a part or all of oxygen atoms of the first layer with nitrogen atoms [0023-0026].

Claim 2: Udagawa teaches the second layer is made of a GaN system compound semiconductor [0026]

Claim 3: Udagawa teaches the first layer is a Ga_2O_3 system single crystal substrate [0021].

Claim 4: Udagawa teaches the first layer is made of Ga_2O_3 , $(\text{In}_x\text{Ga}_{1-x})_2\text{O}_3$ where $0 \leq x < 1$, $(\text{Al}_x\text{Ga}_{1-x})_2\text{O}_3$ where $0 \leq x < 1$, $(\text{In}_x\text{Al}_y\text{Ga}_{1-x-y})_2\text{O}_3$ where $0 \leq x < 1$, $0 \leq y < 1$, and $0 \leq x + y < 1$, or the like, as a main constituent [0025].

Claim 5: Udagawa teaches the second layer is made of GaN , $\text{In}_z\text{Ga}_{1-z}\text{N}$ where $0 \leq z < 1$, $\text{Al}_z\text{Ga}_{1-z}\text{N}$ where $0 \leq z < 1$, $\text{In}_z\text{Al}_p\text{Ga}_{1-z-p}\text{N}$ where $0 \leq z < 1$, $0 \leq p < 1$, and $0 \leq z + p < 1$, or the like, as a main constituent [0027].

Claim 6: Udagawa teaches a semiconductor layer, characterized by comprising:
a first layer made of a Ga_2O_3 system semiconductor;
a second layer made of a GaN system compound semiconductor and obtained by replacing a part or all of 6 oxygen atoms of the first layer with nitrogen atoms; and
a third layer made of an GaN system epitaxial layer and formed on the second layer [0023-0027].

Claim 7: Udagawa teaches a semiconductor layer, characterized by comprising:
a first layer made of a Ga_2O_3 system semiconductor; and
a second layer made of a GaN system compound semiconductor and formed on the first layer [0023-0026].

Claim 8: Udagawa teaches a semiconductor layer, characterized by comprising:
a first layer made of a Ga_2O_3 system semiconductor;
a second layer made of a GaN system compound semiconductor and formed on the first layer; and
a third layer made of an GaN system epitaxial layer and formed on the second layer [0023-0027].

Conclusion

4. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. "Preparation and structural properties for GaN films grown on Si (111) by annealing" by Yang et al. (IDS reference) reads on claims 1,2,4,5 & 7.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to SARAH K. SALERNO whose telephone number is (571)270-1266. The examiner can normally be reached on M-F 8:00-4:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy can be reached on (571) 272-1705. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/S. K. S./
Examiner, Art Unit 2814

/Theresa T. Doan/
Primary Examiner, Art Unit 2814

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